



# R-C Thermal Model Parameters

## DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in PSpice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the PSpice simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the PSpice Platform".

## R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	60.6277	n/a	9.0634
RT2	16.9657	n/a	2.7529
RT3	61.1678	n/a	7.5913
RT4	25.7909	n/a	30.5800
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.4462	n/a	4.1438m
CT2	268.8995m	n/a	279.5026u
CT3	6.2161m	n/a	235.0567m
CT4	1.1289m	n/a	12.3990m

### Note

- n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	13.2515	n/a	4.5694
RF2	47.7764	n/a	19.5812
RF3	39.0007	n/a	23.0159
RF4	63.8732	n/a	3.2135
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	463.4177u	n/a	418.9755u
CF2	2.0264m	n/a	3.7740m
CF3	15.7869m	n/a	15.4965m
CF4	1.1630	n/a	1.0248

Note

- n/a indicates not applicable

